

 	<h2 style="color: #E67E22;">FQB32N20CTM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB32N20CTM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 28A D2PAK
	Datenblätter:  FQB32N20CTM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 1367 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB32N20CTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 28A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1367 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 156W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	28A (Tc)
Rds On (Max) @ Id, Vgs	82 mOhm @ 14A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2220pF @ 25V
Verpackung	Tape & Reel (TR)






































FQB32N20CTM ist neu im Original, Suche FQB32N20CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB32N20CTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB32N20CTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB32N20CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 28A D2PAK</p>	 <p>FQB32N20 FSC FQB32N20 FSC</p>	 <p>FQB32N30 FAIRCHILD FQB32N30 FAIRCHILD</p>	 <p>FQB33N10 F FQB33N10 F</p>
 <p>FQB33N10LTM Fairchild/ON Semiconductor MOSFET N-CH 100V 33A D2PAK</p>	 <p>FQB32N12V2TM Fairchild/ON Semiconductor MOSFET N-CH 120V 32A D2PAK</p>	 <p>FQB33N10L F FQB33N10L F</p>	 <p>FQB32N12V2TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 120V 32A D2PAK</p>

heiße Teile

Mehr

 FQB27N25TM	 FQB27P06	 FQB27P06TM	 FQB27P06TM	 FQB2N50C
 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM
 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM	 FQB30N06	 FQB30N06L
 FQB30N06LTM	 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM	 FQB32N12V2
 FQB32N12V2TM	 FQB32N12V2TM	 FQB32N20	 FQB32N20C	 FQB32N20CTM
 FQB32N30	 FQB33N10	 FQB33N10L	 FQB33N10LTM	 FQB33N10LTM
 FQB33N10TM	 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM
 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10	 FQB34P10TM
 FQB34P10TM	 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM	 FQB3N30TM
 FQB3N30TM	 FQB3N40TM	 FQB3N40TM	 FQB3N60C	 FQB3N80TM

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